

D 45 H1....H12	Si-P	NF/S-L, 30...80V, 10A, 50W, 40MHz	17j	BD 810	17j
D 45 VH1....VH10	Si-P	S-L, lo-sat, 40...100V, 15A, 83W, 50MHz	17j	-	-
D 45 VM1...VM10	Si-P	S-L, lo-sat, 50...100V, 8A, 50W, 50MHz	17j	-	-
D 46 TQ1...TQ2	Si-N	S-L, 650...750V, 12A, 110W	18j	BUW 13 A	18j
D 52	Si-Di	≈BY 133	31a	1N4007	31a
D 56 W1....W2	Si-N	S-L, 1400V, 5A, 78W	23a	BU 208 A	23a
D 78	Si-Di	≈1N4148	31a	1N4148	31a
D 118	Si-Di	≈1N4148	31a	1N4148	31a
D 129	Si-Di	≈BA 127	31a	1N4148	31a
D 147	C-Di	≈BA 136	31a	-	-
D 228	Si-Di	≈BA 159	31a	BA 159	31a
D 232	Si-Di	≈BA 159	31a	BA 159	31a
D 335	Ge-Di	≈AA 119	31a	AA 119	31a
D 336	Si-Di	≈1N4148	31a	1N4148	31a
D 352	Si-Di	≈BA 282	31a	-	-
D 377	Si-Di	≈FDH 600	31a	1N4148	31a
D 380	Se-Di	Dual-Gl		(2x AA 133)	31a
D 473	Si-Di	≈BA 127	31a	1N4148	31a
D 474	Si-Di	≈1N4148	31a	1N4148	31a
D 475	Si-Di	≈1N4148	31a	1N4148	31a
D 491 D	TTL-Logic	4-Segm.-Treiber/driver	14-DIP	-	-
D 764 A	Si-Di	≈BAV 45	31a	(1N4148)	31a
D 797	Si-Di	≈1N4148	31a	1N4148	31a
D 837(A)	Si-Di	≈1N4148	31a	1N4148	31a
D 838	Si-Di	≈BA 159	31a	BA 159	31a
D 1201 A	Si-Di	=1N4002	31a	1N4007	31a
D 1201 B	Si-Di	=1N4003	31a	1N4007	31a
D 1201 D	Si-Di	=1N4004	31a	1N4007	31a
D 1201 F	Si-Di	=1N4001	31a	1N4007	31a
D 1201 M	Si-Di	=1N4005	31a	1N4007	31a
D 1201 N	Si-Di	=1N4006	31a	1N4007	31a
D 1201 P	Si-Di	=1N4007	31a	1N4007	31a
D 1300 A....D	Si-Di	Uni, 150...525V, 0,25A	2c	BA 159	31a
D 2101(S)	Si-Di	TV-Clamp-Diode, 600V, 1A, <700ns	34b	BYD 33 M	31a
D 2103 S,SF	Si-Di	TV-Damper-Diode, 750V, 3A, <500ns	34b	BYW 96 E	31a
				BY 329/1200	17k
D 2201 A....N	Si-Di	Gl, S, 50...800V, 1A, <500ns	31a	BYD 33 M	31a
D 2600 EF,M	Si-Di	TV-Clamp-Di, 550...600V, 0,5A, <700ns	31a	BYD 33 M	31a
D 2601 A....N	Si-Di	TV-Damper-Di, 100...800V, 1A, <500ns	31a	BYD 33 M	31a
D 3202 U	Diac	Ub=25...40V, Ib<25µA, Itsm=2A	31l	-	-
D 3202 Y	Diac	=D 3202 U: Ub=29...35V	31l	-	-

DA....DM

DB 1 A...P	Si-Br	Gl-Br, 50...1000V, 1A	4-DIP	-	-
DC	Ge-P	≈AF 137		AF 239 S	5g
DF 01	C-Di	AFC	31a	-	-
DF 01(M,S)	Si-Br	Gl-Br, 100V, 1A	4-DIP	-	-
DF 02(M,S)	Si-Br	=DF 01(M), 200V	4-DIP	-	-
DF 04(M,S)	Si-Br	=DF 01(M): 400V	4-DIP	-	-
DF 005(M,S)	Si-Br	=DF 01(M): 50V	4-DIP	-	-
DF 06(M,S)	Si-Br	=DF 01(M): 600V	4-DIP	-	-
DF 08(M,S)	Si-Br	=DF 01(M): 800V	4-DIP	-	-
DF 10(M,S)	Si-Br	=DF 01(M): 1000V	4-DIP	-	-
DFA 007	Ge-Di	≈AA 143	31a	AA 138	31a
DFB 03 R, T,W	Si-Di	Gl, 1500...2000V, 0,3A, <1µs	31a	BY 203/20	31a